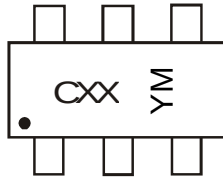


Marking Information

SOT363



CXX = Product Type Marking Code
YM = Date Code Marking
Y = Year (ex: F = 2018)
M = Month (ex: 9 = September)

Date Code Key

Year	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028
Code	F	G	H	I	J	K	L	M	N	O	P

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Absolute Maximum Ratings NPN Section (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Supply Voltage <Pin: (6) to (1)>	V _{CC}	50	V
Input Voltage <Pin: (2) to (1)>	V _{IN}	-10 to +40 -10 to +40 -6 to +40 -5 to +12 -10 to +40 -5V Max -10 to +30 -5V Max -10 to +30 -10 to +40	V
Output Current	I _O	30 30 70 100 50 100 100 100 100 20	mA
Output Current	I _C (Max)	100	mA

Absolute Maximum Ratings PNP Section (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Supply Voltage <Pin: (4) to (3)>		V _{CC}	50	V
Input Voltage <Pin: (5) to (4)>	DCX124EU	V _{IN}	+10 to -40	V
	DCX144EU		+10 to -40	
	DCX114YU		+6 to -40	
	DCX123JU		+5 to -12	
	DCX114EU		+10 to -40	
	DCX143TU		+5V Max	
	DCX143EU		+10 to -30	
	DCX114TU		+5V Max	
	DCX143ZU		+5 to -30	
	DCX115EU		+10 to -40	
Output Current	DCX124EU	I _O	-30	mA
	DCX144EU		-30	
	DCX114YU		-70	
	DCX123JU		-100	
	DCX114EU		-50	
	DCX143TU		-100	
	DCX143EU		-100	
	DCX114TU		-100	
	DCX143ZU		-100	
	DCX115EU		-20	
Output Current		I _C (Max)	-100	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Notes 7 & 8)	P _D	200	mW
Thermal Resistance, Junction to Ambient Air (Note 7)	R _{θJA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes: 7. Mounted on FR-4 PC Board with minimum recommended pad layout.
8. 150mW per element must not be exceeded.

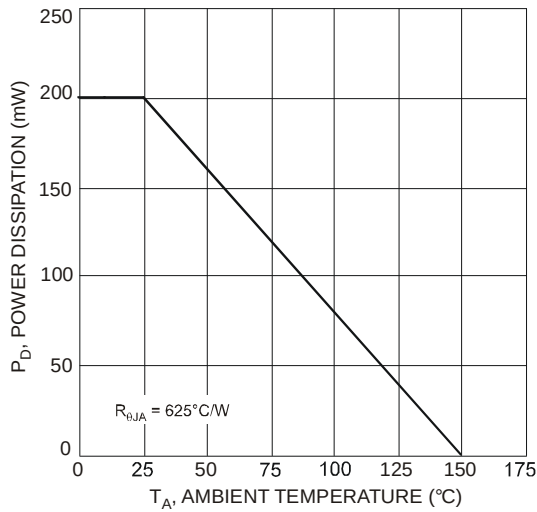
Electrical Characteristics NPN Section (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
R1 Only (DCX143TU & DCX114TU)							
Collector-Base Breakdown Voltage		BV _{CBO}	50	—	—	V	I _C = 50μA
Collector-Emitter Breakdown Voltage		BV _{CEO}	50	—	—	V	I _C = 1mA
Emitter-Base Breakdown Voltage		BV _{EBO}	5	—	—	V	I _E = 50μA
Collector Cutoff Current		I _{CBO}	—	—	0.5	μA	V _{CB} = 50V
Emitter Cutoff Current		I _{EBO}	—	—	0.5	μA	V _{EB} = 4V
Collector-Emitter Saturation Voltage		V _{CE(SAT)}	—	—	0.3	V	I _C /I _B = 2.5mA / 0.25mA DCX143TU I _C /I _B = 1mA / 0.1mA DCX114TU
DC Current Transfer Ratio		h _{FE}	100	250	600	—	I _C = 1mA, V _{CE} = 5V
Input Resistor (R ₁) Tolerance		ΔR ₁	-30	—	+30	%	—
Gain-Bandwidth Product		f _T	—	250	—	MHz	V _{CE} = 10V, I _E = -5mA, f = 100MHz
R1/R2 Only							
Input Voltage	DCX124EU	V _{I(OFF)}	0.5	1.1	—	V	V _{CC} = 5V, I _O = 100μA
	DCX144EU		0.5	1.1			
	DCX114YU		0.3	—			
	DCX123JU		0.5	—			
	DCX114EU		0.5	1.1			
	DCX143EU		0.5	1.16			
	DCX143ZU		0.5	—			
	DCX115EU		0.5	—			
	DCX124EU	V _{I(ON)}	—	1.9	3.0		V _O = 0.3V, I _O = 5mA
	DCX144EU			1.9	3.0		V _O = 0.3V, I _O = 2mA
	DCX114YU			—	1.4		V _O = 0.3V, I _O = 1mA
	DCX123JU			—	1.1		V _O = 0.3V, I _O = 5mA
	DCX114EU			1.9	3.0		V _O = 0.3V, I _O = 10mA
	DCX143EU			1.99	3.0		V _O = 0.3V, I _O = 20mA
	DCX143ZU			—	1.3		V _O = 0.3V, I _O = 5mA
	DCX115EU			—	3		V _O = 0.3V, I _O = 1mA
Output Voltage	DCX124EU	V _{O(ON)}	—	0.1	0.3	V	I _O /I _I = 10mA / 0.5mA
	DCX144EU						I _O /I _I = 10mA / 0.5mA
	DCX114YU						I _O /I _I = 5mA / 0.25mA
	DCX123JU						I _O /I _I = 5mA / 0.25mA
	DCX114EU						I _O /I _I = 10mA / 0.5mA
	DCX143EU						I _O /I _I = 10mA / 0.5mA
	DCX143ZU						I _O /I _I = 5mA / 0.25mA
	DCX115EU						I _O /I _I = 10mA / 0.5mA
Input Current	DCX124EU	I _I	—	—	0.36	mA	V _I = 5V
	DCX144EU				0.18		
	DCX114YU				0.88		
	DCX123JU				3.6		
	DCX114EU				0.88		
	DCX143EU				0.88		
	DCX143ZU				1.8		
	DCX115EU				0.15		
Output Current		I _{O(OFF)}	—	—	0.5	μA	V _{CC} = 50V, V _I = 0V
DC Current Gain	DCX124EU	G _I	56	—	—	—	V _O = 5V, I _O = 5mA
	DCX124EUQ		60				V _O = 5V, I _O = 5mA
	DCX144EU		68				V _O = 5V, I _O = 5mA
	DCX114YU		68				V _O = 5V, I _O = 10mA
	DCX114YUQ		80				V _O = 5V, I _O = 10mA
	DCX123JU		80				V _O = 5V, I _O = 10mA
	DCX114EU		30				V _O = 5V, I _O = 5mA
	DCX143EU		50				V _O = 5V, I _O = 10mA
	DCX143ZU		80				V _O = 5V, I _O = 10mA
	DCX115EU		82				V _O = 5V, I _O = 5mA
Input Resistor (R ₁) Tolerance		ΔR ₁	-30	—	+30	%	—
Resistance Ratio Tolerance		ΔR ₂ /R ₁	-20	—	+20	%	—
Gain-Bandwidth Product		f _T	—	250	—	MHz	V _{CE} = 10V, I _E = 5mA, f = 100MHz

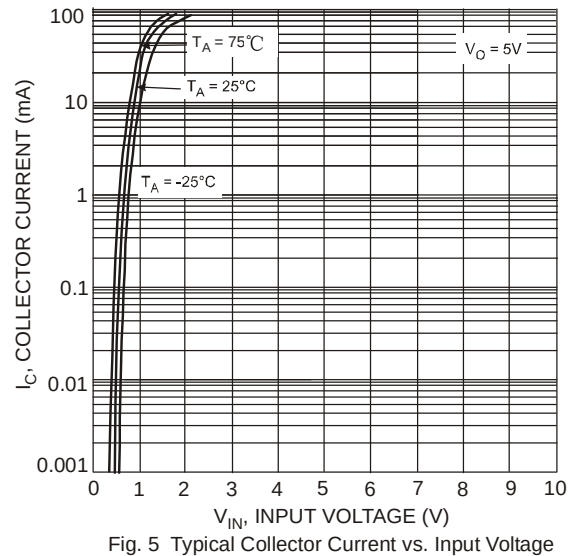
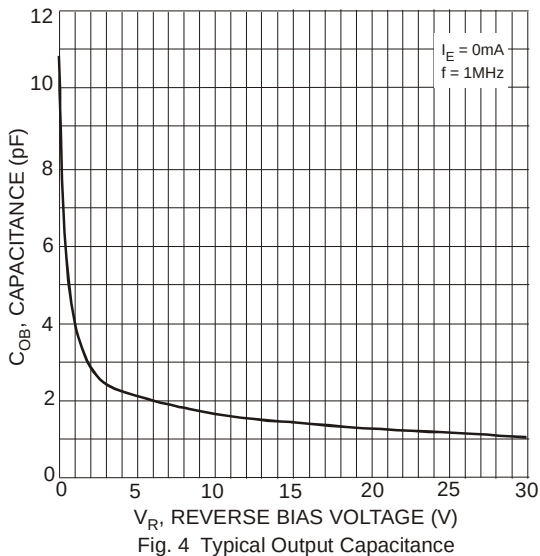
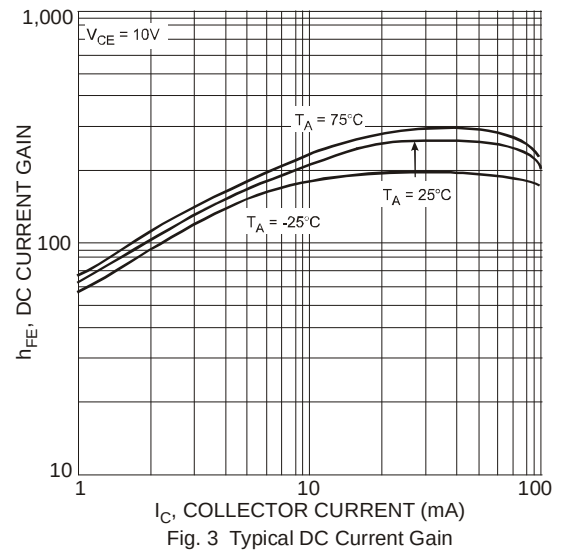
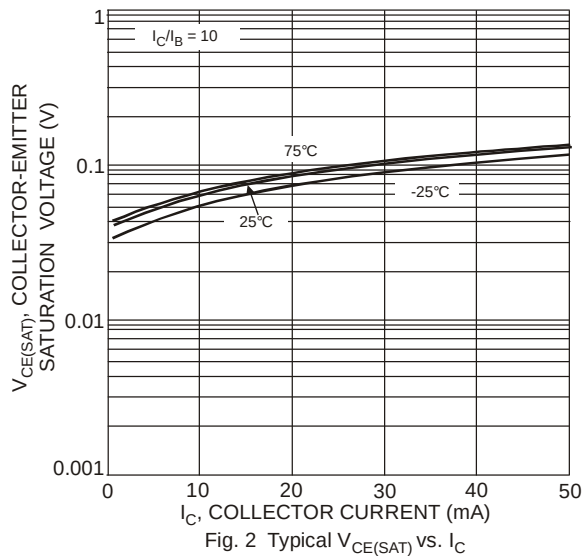
Electrical Characteristics PNP Section (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
R1 Only (DCX143TU & DCX114TU)							
Collector-Base Breakdown Voltage		BV _{CBO}	-50	—	—	V	I _C = -50μA
Collector-Emitter Breakdown Voltage		BV _{CEO}	-50	—	—	V	I _C = -1mA
Emitter-Base Breakdown Voltage		BV _{EBO}	-5	—	—	V	I _E = -50μA
Collector Cutoff Current		I _{CBO}	—	—	-0.5	μA	V _{CB} = -50V
Emitter Cutoff Current		I _{EBO}	—	—	-0.5	μA	V _{EB} = -4V
Collector-Emitter Saturation Voltage		V _{CE(SAT)}	—	—	-0.3	V	I _C /I _B = 2.5mA / 0.25mA DCX143TU I _C /I _B = 1mA / 0.1mA DCX114TU
DC Current Transfer Ratio		h _{FE}	100	250	600	—	I _C = -1mA, V _{CE} = -5V
Input Resistor (R ₁) Tolerance		ΔR ₁	-30	—	+30	%	—
Gain-Bandwidth Product		f _T	—	250	—	MHz	V _{CE} = -10V, I _E = 5mA, f = 100MHz
R1/R2 Only							
Input Voltage	DCX124EU	V _{I(OFF)}	-0.5	-1.1	—	V	V _{CC} = -5V, I _O = -100μA
	DCX144EU		-0.5	-1.1			
	DCX114YU		-0.3	—			
	DCX123JU		-0.5	—			
	DCX114EU		-0.5	-1.1			
	DCX143EU		-0.5	-1.16			
	DCX143ZU		-0.5	—			
	DCX115EU		-0.5	—			
	DCX124EU	V _{I(ON)}	—	-1.9	-3.0		V _O = -0.3V, I _O = -5mA
	DCX144EU		—	-1.9	-3.0		V _O = -0.3V, I _O = -2mA
	DCX114YU		—	—	-1.4		V _O = -0.3V, I _O = -1mA
	DCX123JU		—	—	-1.1		V _O = -0.3V, I _O = -5mA
	DCX114EU		—	-1.9	-3.0		V _O = -0.3V, I _O = -10mA
	DCX143EU		—	-2.5	-3.0		V _O = -0.3V, I _O = -20mA
	DCX143ZU		—	—	-1.3		V _O = -0.3V, I _O = -5mA
	DCX115EU		—	—	-3		V _O = -0.3V, I _O = -1mA
Output Voltage	DCX124EU	V _{O(ON)}	—	-0.1	-0.3	V	I _O /I _I = -10mA / -0.5mA
	DCX144EU						I _O /I _I = -10mA / -0.5mA
	DCX114YU						I _O /I _I = -5mA / -0.25mA
	DCX123JU						I _O /I _I = -5mA / -0.25mA
	DCX114EU						I _O /I _I = -10mA / -0.5mA
	DCX143EU						I _O /I _I = -10mA / -0.5mA
	DCX143ZU						I _O /I _I = -5mA / -0.25mA
	DCX115EU						I _O /I _I = -10mA / -0.5mA
Input Current	DCX124EU	I _I	—	—	-0.36 -0.18 -0.88 -3.6 -0.88 -0.88 -1.8 -0.15	mA	V _I = -5V
	DCX144EU						
	DCX114YU						
	DCX123JU						
	DCX114EU						
	DCX143EU						
	DCX143ZU						
	DCX115EU						
Output Current		I _{O(OFF)}	—	—	-0.5	μA	V _{CC} = 50V, V _I = 0V
DC Current Gain	DCX124EU	G _I	—	—	—	—	V _O = -5V, I _O = -5mA
	DCX124EUQ						V _O = -5V, I _O = -5mA
	DCX144EU						V _O = -5V, I _O = -5mA
	DCX114YU						V _O = -5V, I _O = -10mA
	DCX114YUQ						V _O = -5V, I _O = -10mA
	DCX123JU						V _O = -5V, I _O = -10mA
	DCX114EU						V _O = -5V, I _O = -5mA
	DCX143EU						V _O = -5V, I _O = -10mA
	DCX143ZU						V _O = -5V, I _O = -10mA
	DCX115EU						V _O = -5V, I _O = -5mA
Input Resistor (R ₁) Tolerance		ΔR ₁	-30	—	+30	%	—
Resistance Ratio Tolerance		ΔR ₂ /R ₁	-20	—	+20	%	—
Gain-Bandwidth Product		f _T	—	250	—	MHz	V _{CE} = -10V, I _E = -5mA, f = 100MHz

Typical Curves – Total Device



Typical Curves – DCX123JU PNP Section (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Typical Curves – DCX123JU PNP Section (Cont.)

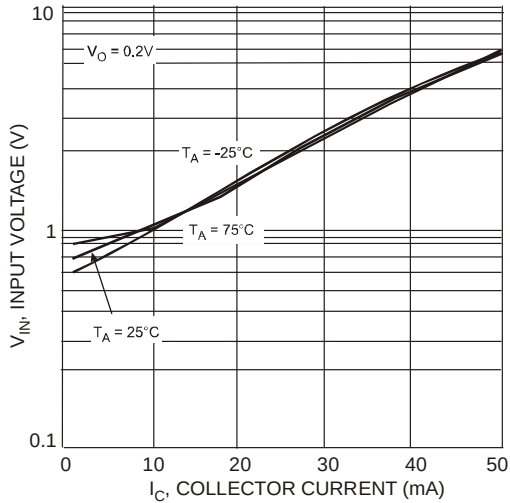


Fig. 6 Typical Input Voltage vs. Collector Current

Typical Curves – DCX123JU NPN Section (@ $T_A = +25^\circ C$, unless otherwise specified.)

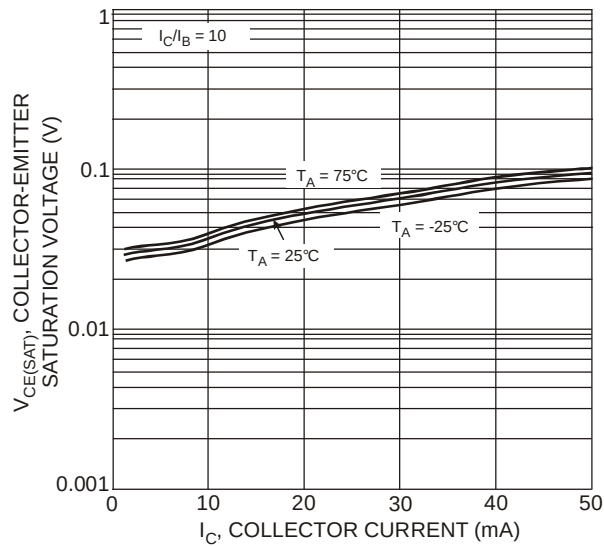


Fig. 7 Typical $V_{CE(SAT)}$ vs. I_C

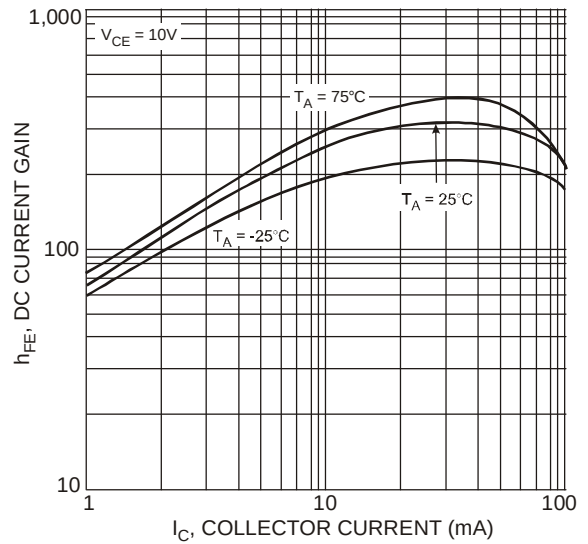


Fig. 8 Typical DC Current Gain

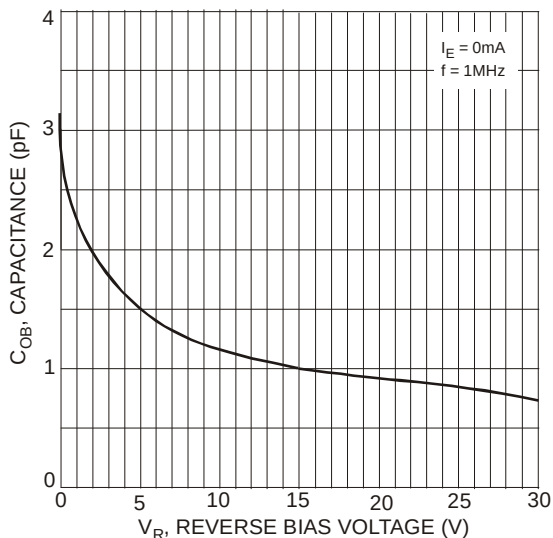


Fig. 9 Typical Output Capacitance

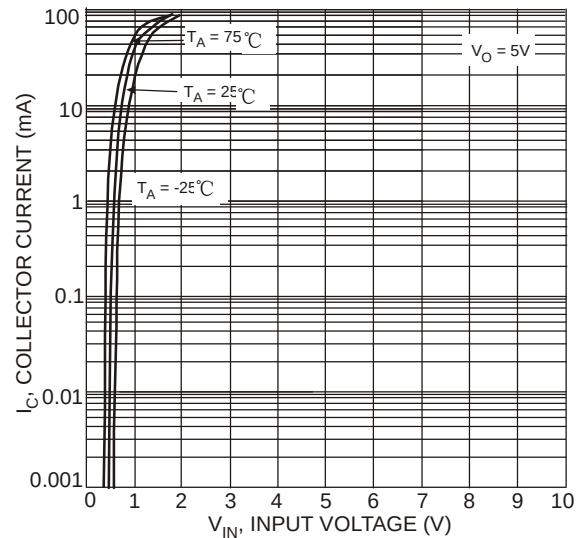
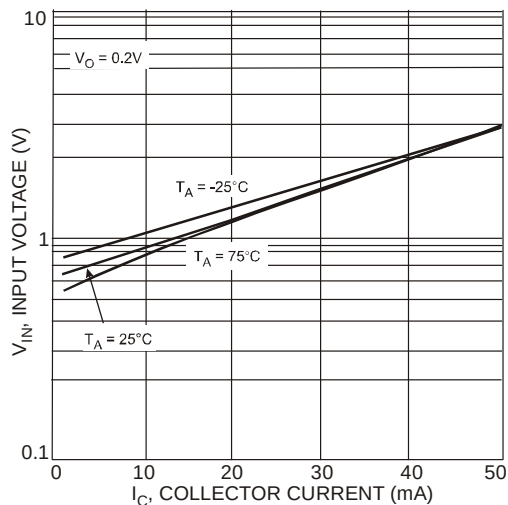
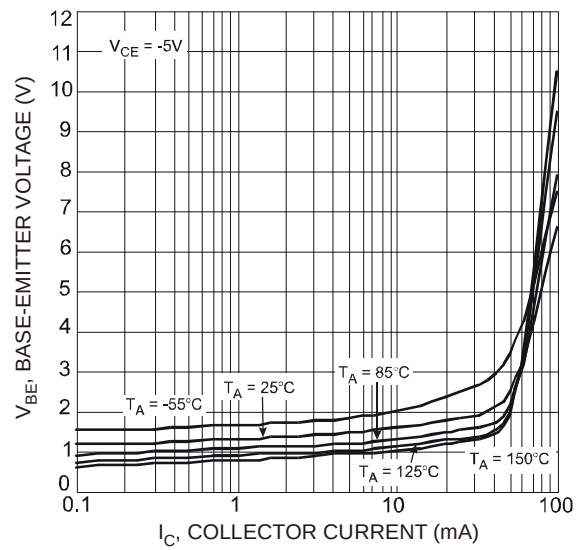
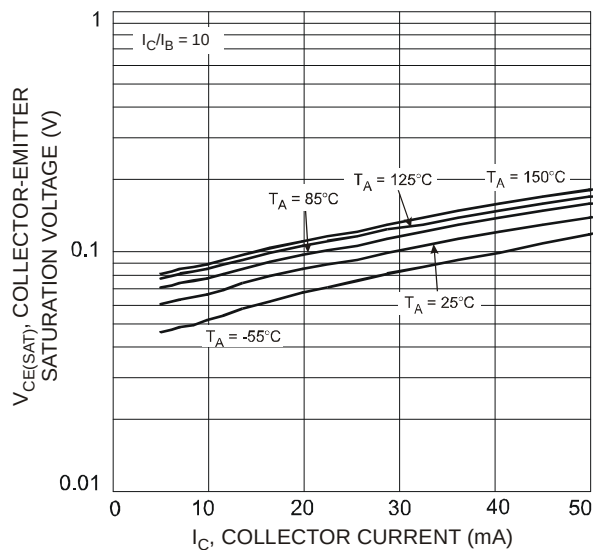
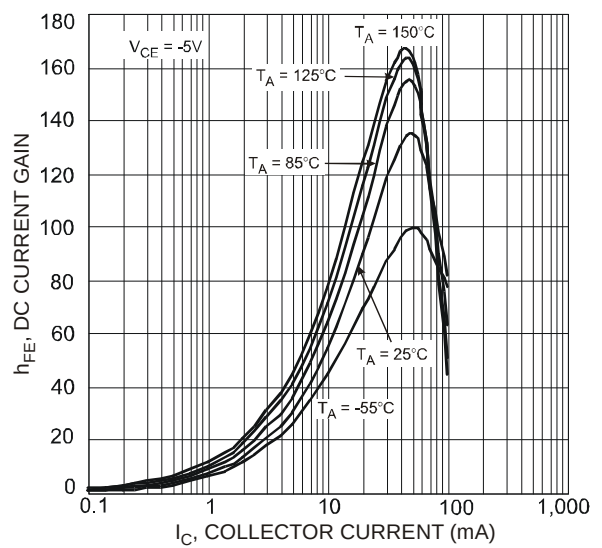
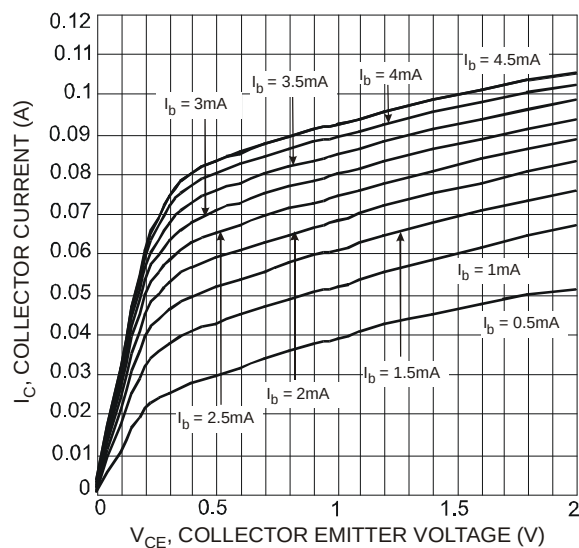


Fig. 10 Typical Collector Current vs. Input Voltage

Typical Curves – DCX123JU NPN Section (Cont.)



Typical Curves – DCX143EU PNP Section (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Typical Curves – DCX143EU PNP Section (Cont.)

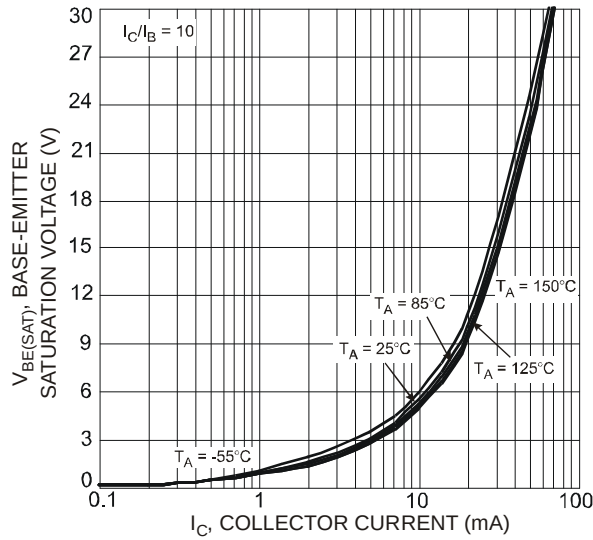


Fig. 16 Typical $V_{BE(SAT)}$ vs. I_C

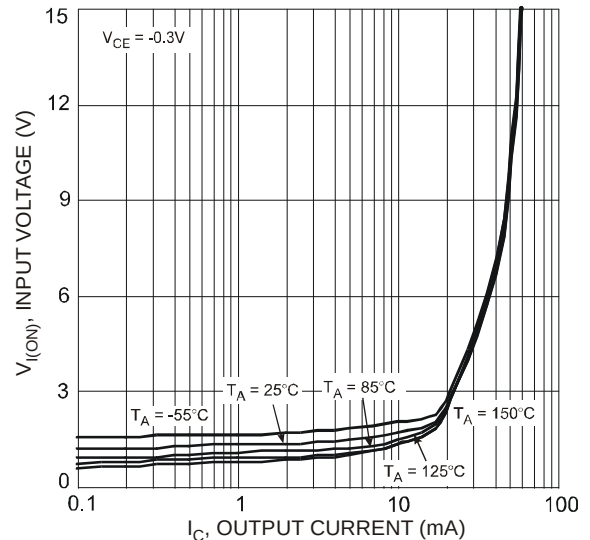


Fig. 17 Typical $V_{I(ON)}$ vs. I_C

Typical Curves – DCX143EU NPN Section (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

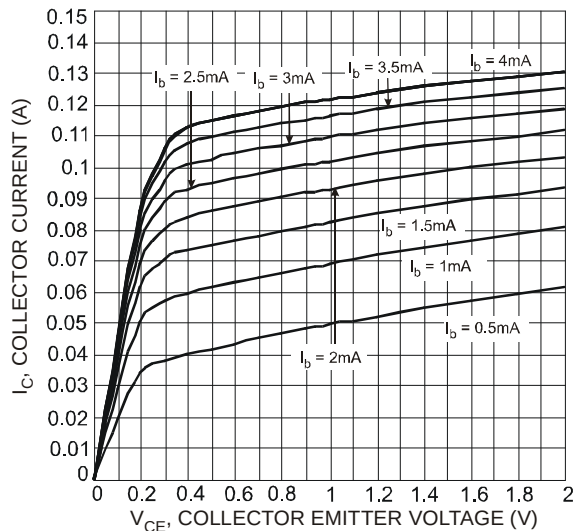


Fig. 18 Typical V_{CE} vs. I_C

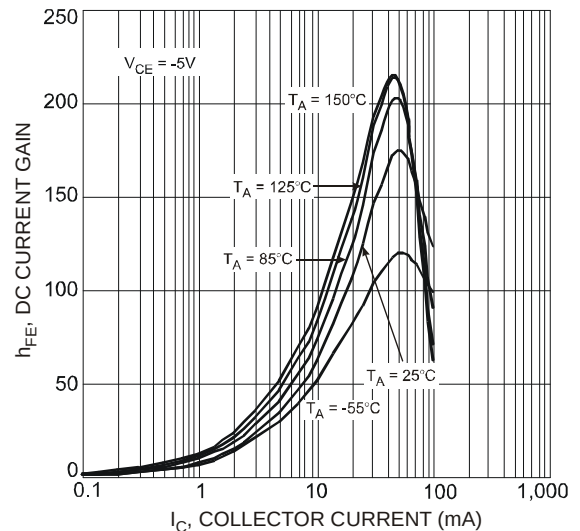


Fig. 19 Typical DC Current Gain

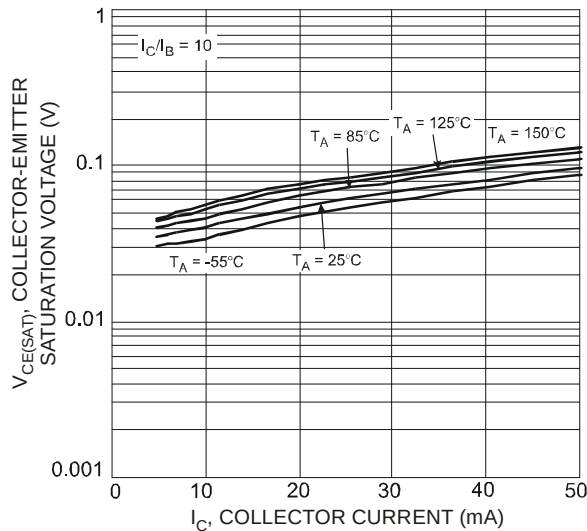


Fig. 20 Typical $V_{CE(SAT)}$ vs. I_C

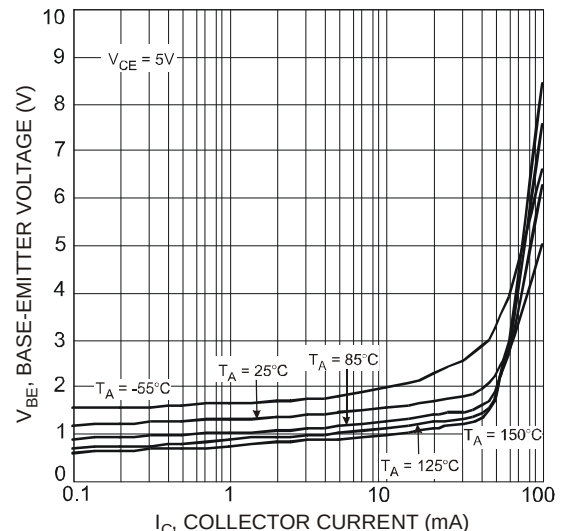
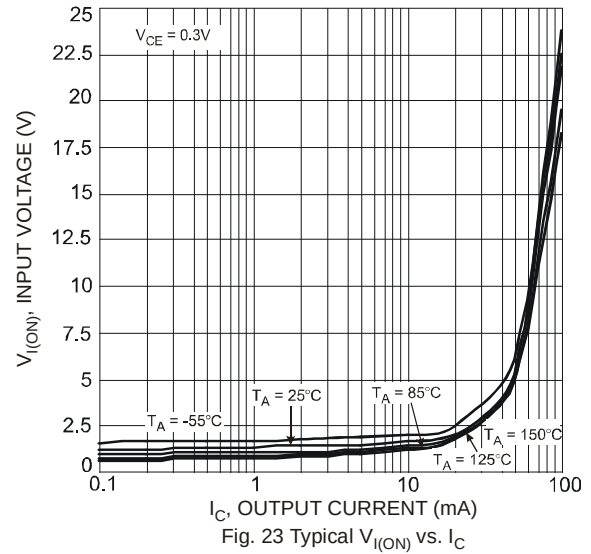
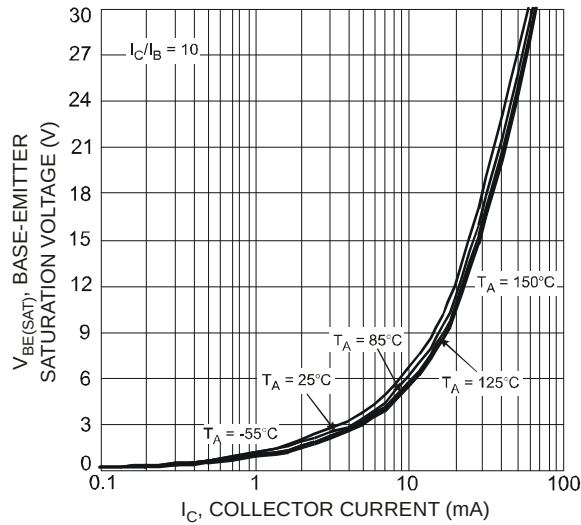
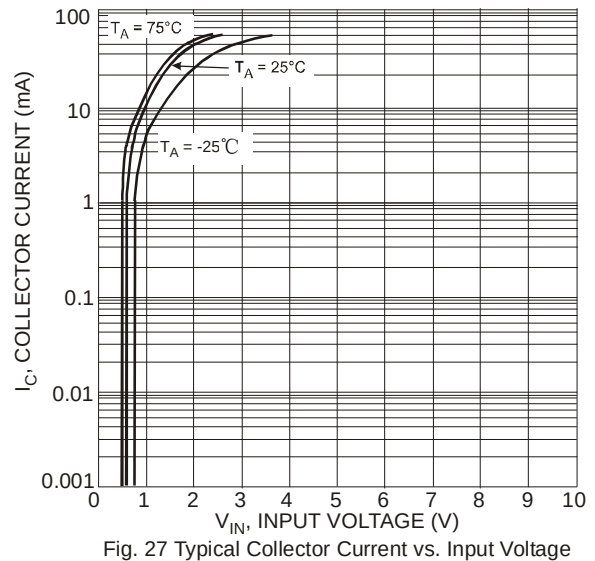
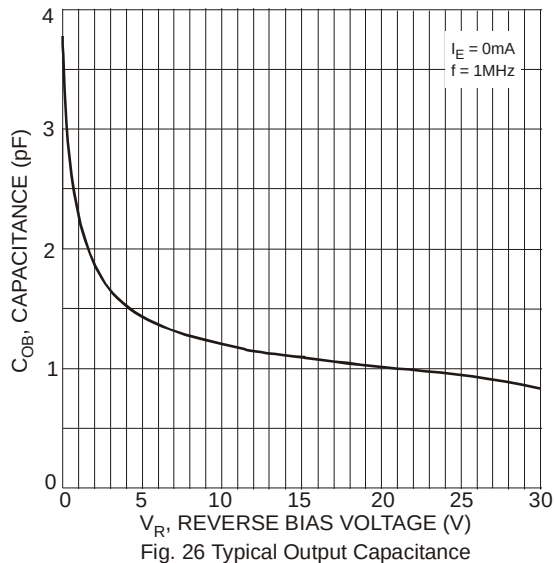
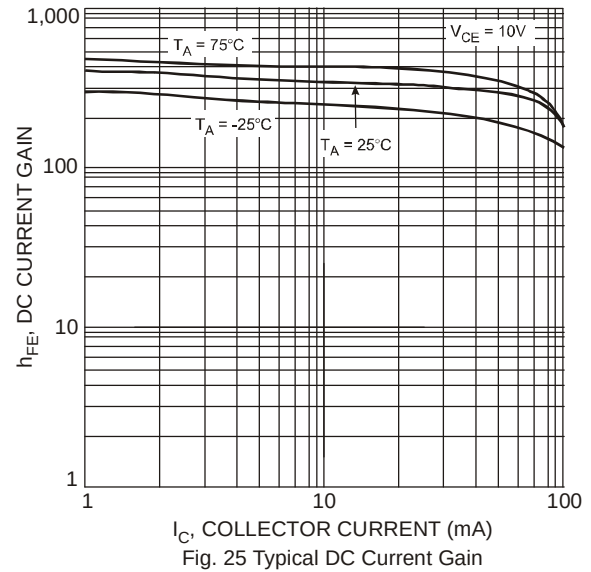
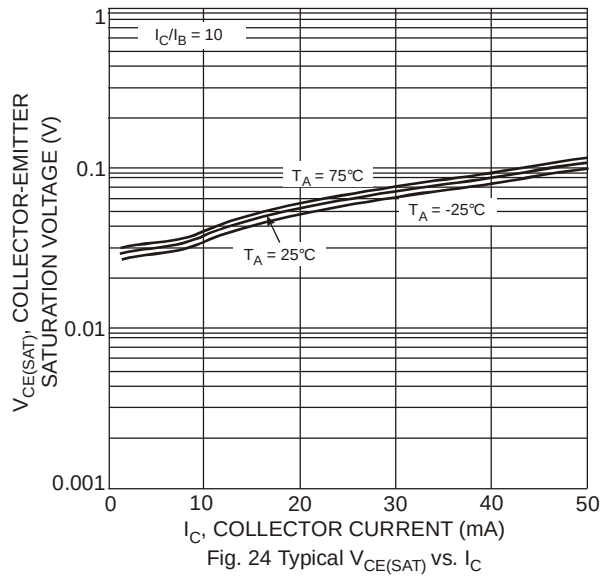


Fig. 21 Typical V_{BE} vs. I_C

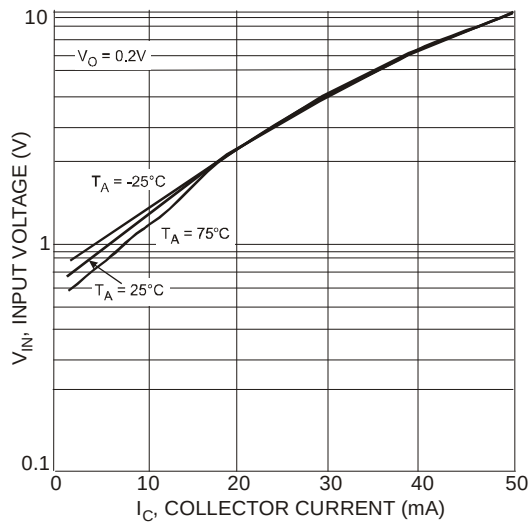
Typical Curves – DCX143EU NPN Section (Cont.)



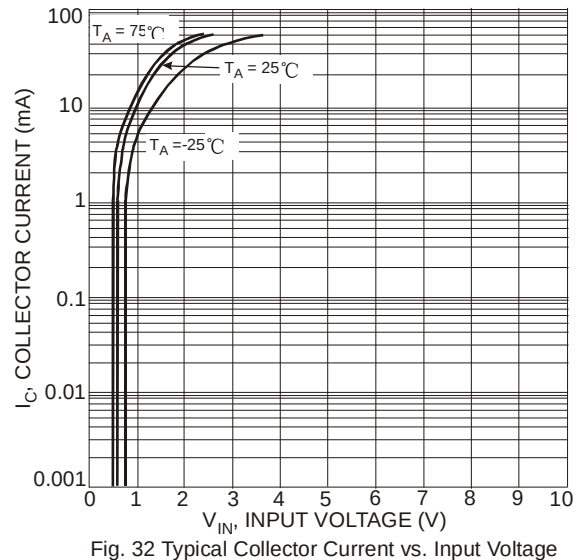
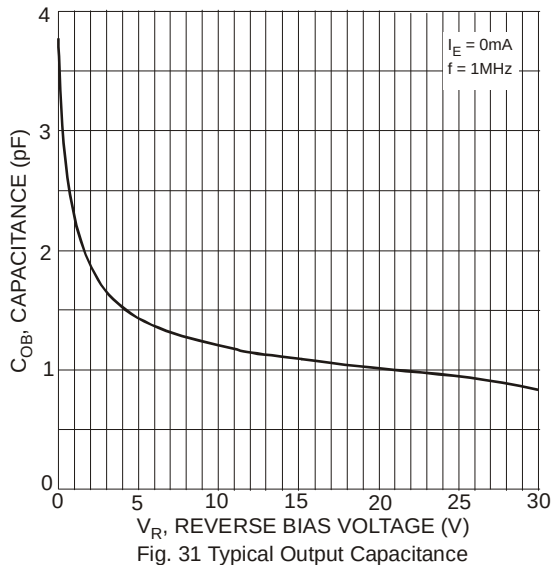
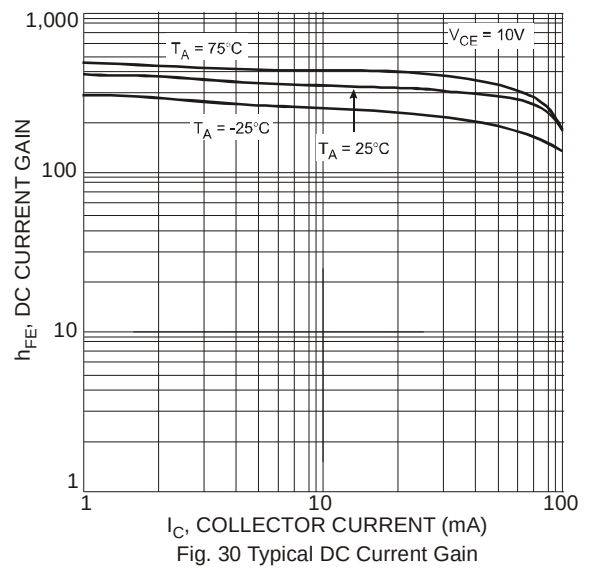
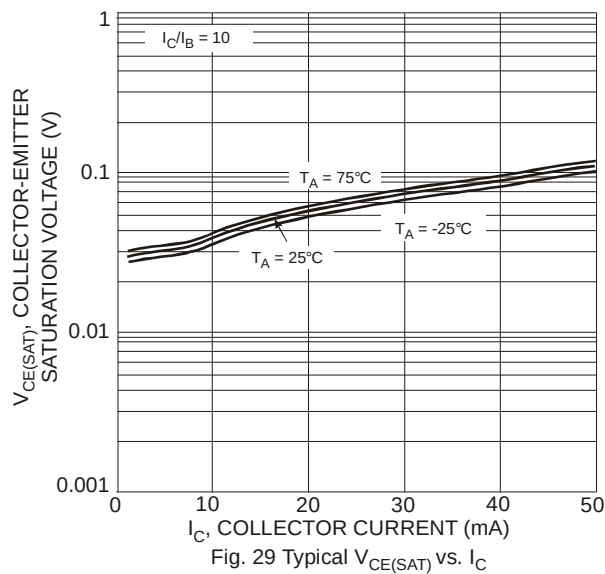
Typical Curves – DCX114TU PNP Section (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Typical Curves – DCX114TU PNP Section (Cont.)



Typical Curves – DCX114TU NPN Section (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Typical Curves – DCX114TU NPN Section (Cont.)

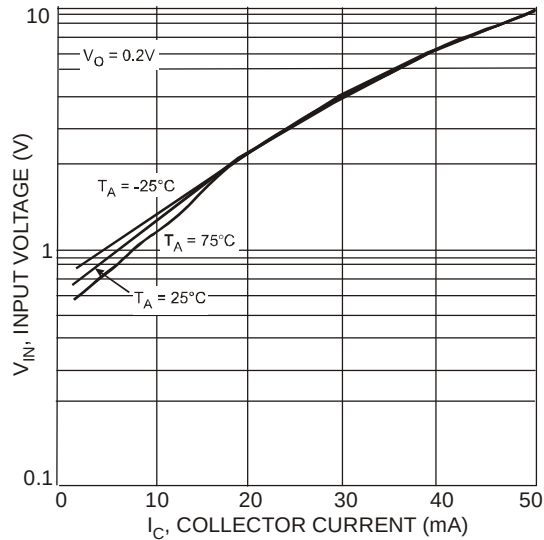
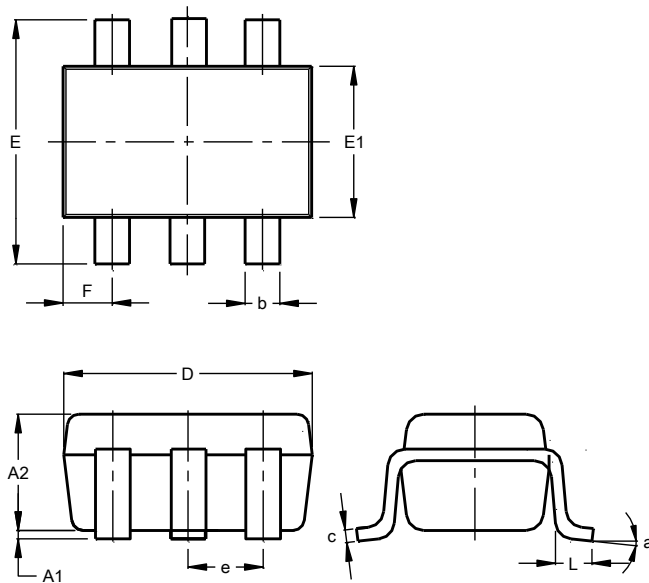


Fig. 33 Typical Input Voltage vs. Collector Current

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

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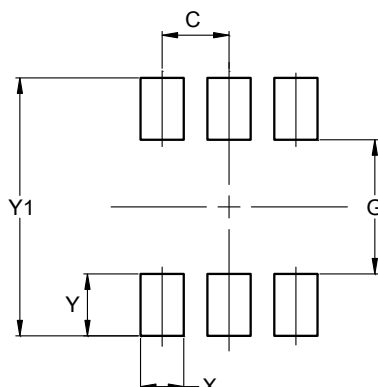


SOT363			
Dim	Min	Max	Typ
A1	0.00	0.10	0.05
A2	0.90	1.00	0.95
b	0.10	0.30	0.25
c	0.10	0.22	0.11
D	1.80	2.20	2.15
E	2.00	2.20	2.10
E1	1.15	1.35	1.30
e	0.650 BSC		
F	0.40	0.45	0.425
L	0.25	0.40	0.30
a	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT363



Dimensions	Value (in mm)
C	0.650
G	1.300
X	0.420
Y	0.600
Y1	2.500

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